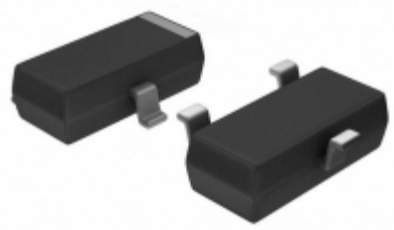









	FJV3104RMTF	
	Hersteller-Teilenummer:	FJV3104RMTF
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	TRANS PREBIAS NPN 200MW SOT23-3
	Datenblätter:	1.FJV3104RMTF.pdf 2.FJV3104RMTF.pdf
	RoHs Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, 476770 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FJV3104RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	476770 pcs Stock
Hersteller Standard Vorlaufzeit	2 Weeks
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) NPN - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	68 @ 5mA, 5V
Frequenz - Übergang	250MHz
Verpackung	Cut Tape (CT)
Basisteilenummer	FJV3104
Widerstand - Basis (R1)	47 kOhms
Widerstand - Emitterbasis (R2)	47 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FJV3104RMTFCT

FJV3104RMTF ist neu im Original, Suche FJV3104RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3104RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3104RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 FJV3102RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 0.2W SOT23-3	 FJV3106RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3105RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3103RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3
 FJV3101RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3104RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3103RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3102RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 0.2W SOT23-3

heiße Teile

Mehr

⊕ FJV1845EMTF	↔ FJV1845EMTF	⇒ FJV1845FMTF	D FJV1845FMTF	⇒ FJV1845PMTF
⊕ FJV1845PMTF	⊕ FJV1845UMTF	D FJV1845UMTF	⇒ FJV3101RLIMTF	⇒ FJV3101RMTF
⊕ FJV3101RMTF	⊕ FJV3102RMTF	⊕ FJV3102RMTF	↔ FJV3103RMTF	⇒ FJV3103RMTF
D FJV3104RMTF	⊕ FJV3105RMTF	⊕ FJV3105RMTF	⊕ FJV3106RMTF	⇒ FJV3106RMTF
⇒ FJV3107RMTF	↔ FJV3107RMTF	⊕ FJV3108RMTF	⊕ FJV3108RMTF	⇒ FJV3109R
↔ FJV3109RMTF	⇒ FJV3109RMTF	D FJV3110RMTF	⊕ FJV3110RMTF	⊕ FJV3111RMTF
⊕ FJV3111RMTF	D FJV3112RMTF	⇒ FJV3112RMTF	↔ FJV3113RMTF	⇒ FJV3113RMTF
⊕ FJV3114RMTF	⊕ FJV3114RMTF	↔ FJV3115RMTF	⇒ FJV3115RMTF	⇒ FJV4101RMTF
⊕ FJV4101RMTF	⊕ FJV4102RLIMTF	⊕ FJV4102RMTF	D FJV4102RMTF	⇒ FJV4103RMTF
↔ FJV4103RMTF	⊕ FJV4104RMTF	⊕ FJV4104RMTF	⊕ FJV4105RMTF	⇒ FJV4105RMTF

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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